	Application No.	Applicant(s)	
Notice of Allowability	09/839,941	39,941 D'EVELYN ET AL.	
	Examin r	Art Unit	1
	Wai-Sing Louie	2814	Bu
The MAILING DATE of this communication apper All claims being allowable, PROSECUTION ON THE MERITS IS (herewith (or previously mailed), a Notice of Allowance (PTOL-85) NOTICE OF ALLOWABILITY IS NOT A GRANT OF PATENT RIG of the Office or upon petition by the applicant. See 37 CFR 1.313	(OR REMAINS) CLOSED in this ap or other appropriate communicatior GHTS. This application is subject to	plication. If not included will be mailed in due o	d course. THIS
1. This communication is responsive to 4/21/04.			
2. The allowed claim(s) is/are 1-49,59-106,124 and 125.			
3. \boxtimes The drawings filed on <u>20 April 2001</u> are accepted by the Ex	aminer.		
 4. Acknowledgment is made of a claim for foreign priority un a) All b) Some* c) None of the: 1. Certified copies of the priority documents have 2. Certified copies of the priority documents have 3. Copies of the certified copies of the priority documents have International Bureau (PCT Rule 17.2(a)). * Certified copies not received: 	been received. been received in Application No		on from the
Applicant has THREE MONTHS FROM THE "MAILING DATE" of noted below. Failure to timely comply will result in ABANDONM THIS THREE-MONTH PERIOD IS NOT EXTENDABLE.		complying with the req	uirements
5. A SUBSTITUTE OATH OR DECLARATION must be submit INFORMAL PATENT APPLICATION (PTO-152) which give			OTICE OF
6. CORRECTED DRAWINGS (as "replacement sheets") must (a) including changes required by the Notice of Draftsperse 1) hereto or 2) to Paper No./Mail Date (b) including changes required by the attached Examiner's Paper No./Mail Date ldentifying indicia such as the application number (see 37 CFR 1. each sheet. Replacement sheet(s) should be labeled as such in the post of the standard of the post of the standard of the post of the standard of	on's Patent Drawing Review (PTO- s Amendment / Comment or in the C 84(c)) should be written on the drawing to header according to 37 CFR 1.121(sit of BIOLOGICAL MATERIAL r	Office action of ngs in the front (not the l d). must be submitted. N	
Attachment(s) 1. Notice of References Cited (PTO-892) 2. Notice of Draftperson's Patent Drawing Review (PTO-948) 3. Information Disclosure Statements (PTO-1449 or PTO/SB/02 Paper No./Mail Date 4. Examiner's Comment Regarding Requirement for Deposit of Biological Material	5. Notice of Informal F 6. Interview Summary Paper No./Mail Da 8), 7. Examiner's Amenda 8. Examiner's Stateme 9. Other	(PTO-413), te ment/Comment	·

DETAILED ACTION

The arguments in the appeal brief has overcome the rejection of the previous office action and claims 1-49, 59-106, 124 and 125 are allowed.

Allowable Subject Matter

The following is an examiner's statement of reasons for allowance:

The claimed invention is a photodetector, the photodetector comprising:

- a) A substrate, the substrate comprising a homoepitaxially grown single crystal gallium nitride wafer having a dislocation density of less than 10³ cm⁻²,
- b) At least one active layer disposed on the substrate;
- c) At least one conductive contact structure affixed to at least one of the substrate and the at least one active layer.

Reference Chen (US 6,104,074) discloses a gallium nitride layer grown on a sapphire substrate, but does not disclose a homoepitaxially grown single crystal gallium nitride wafer.

Chen do not disclose the gallium nitride substrate has a dislocation density of less than 10³ cm⁻².

Reference Tischler et al. (US 5,679,152) do not disclose a homoepitaxially grown single crystal gallium nitride wafer and the semiconductor structure having an active layer.

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Reference Tadatomo et al. (US 6,225,650) disclose a gallium nitride layer grown on a sapphire substrate, but does not disclose a homoepitaxially grown single crystal gallium nitride wafer.

Therefore, the above references do not disclose the claimed invention of present application and claims 1-49, 59-106, 124 and 125 are allowed.

Any comments considered necessary by applicant must be submitted no later than the payment of the issue fee and, to avoid processing delays, should preferably accompany the issue fee. Such submissions should be clearly labeled "Comments on Statement of Reasons for Allowance."

Any inquiry concerning this communication or earlier communications from the examiner should be directed to Wai-Sing Louie whose telephone number is (571) 272-1709. The examiner can normally be reached on 7:30 AM to 4:00 PM.

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Wael Fahmy can be reached on (571) 272-1705. The fax phone number for the organization where this application or proceeding is assigned is 703-872-9306.

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Information regarding the status of an application may be obtained from the Patent Application Information Retrieval (PAIR) system. Status information for published applications may be obtained from either Private PAIR or Public PAIR. Status information for unpublished applications is available through Private PAIR only. For more information about the PAIR system, see http://pair-direct.uspto.gov. Should you have questions on access to the Private PAIR system, contact the Electronic Business Center (EBC) at 866-217-9197 (toll-free).

Wsl

May 28, 2004.

YONG PHAM YONG PHAM EXAMINER